

LAPPD magnetic field test results

CERN MNP-17, Nov. 2023

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remote

Why measuring LAPPD response in magnetic field

- Large Area **Picosecond** Photodetectors were expected to operate in magnetic fields,
- smaller MCPs from other brands ???,
- RICH and PET applications require detector tolerance to about 1 T magnetic fields,
- it is already established that LAPPD gain drops in magnetic field, but can be recovered by higher bias voltage,
- it is yet not clear whether efficiency, timing and spacial resolutions are also affected,
- we decided to verify it on MNP-17 magnet at CERN.

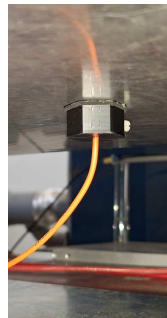
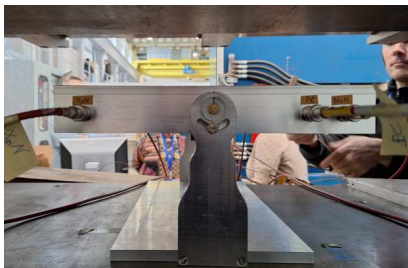
MNP-17 magnet in B-168 at CERN

- 0.5 T dipole magnet with 30 cm gap height,
- current-to-magnetic field calibration, water cooling,
- 1D Hall-probe available.



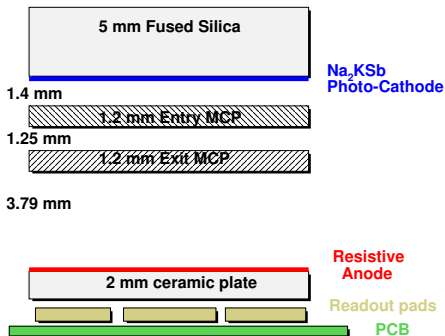
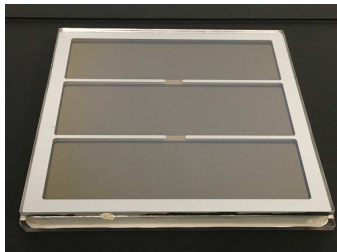
Measurement setup

- PicoQuant 405 nm laser connected by optical fiber,
- 10 μm pore LAPPD N.153 in inclinable dark box,
- 3D Hall-probe.

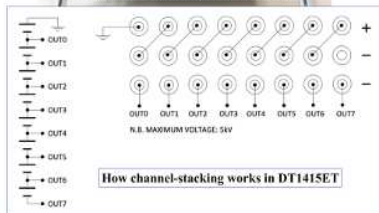


LAPPD N.153

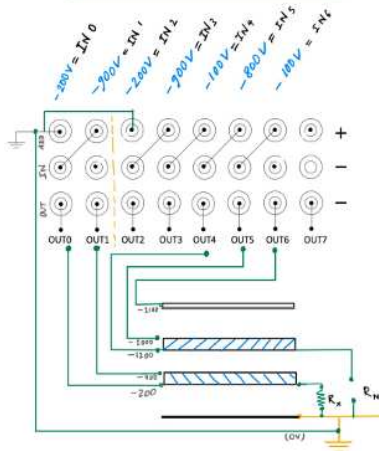
- Gen II, 10 μm capillary, short stack, Multi-Alkali,
- ROP 50/875/200/875/200, gain 7.45×10^6 , TTS SPE 68 ps,
- MCP maximum bias 900 V, 5.5 M Ω /MCP,
- Dark Count Rate (th. 4 mV) 2.1 kHz/cm² over 373 cm², means 0.76 kHz/6 mm pad,
- QE(405 nm) \simeq 18% (max. at 365 nm 25%).



LAPPD bias voltages



How we used it: An example set of voltages

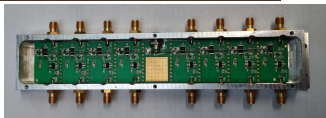
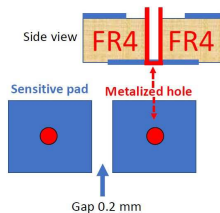


LAPPD readout

- LAPPD is capacitively coupled to PCB pads,
- PCB pads are directly connected to amplifiers,
- 1 GHz amplifiers have 20 dB gain, 0.22 mV noise and $<0.2\%$ cross-talk.

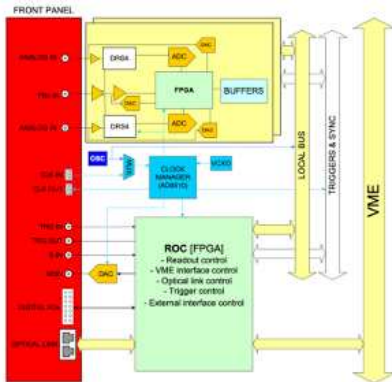
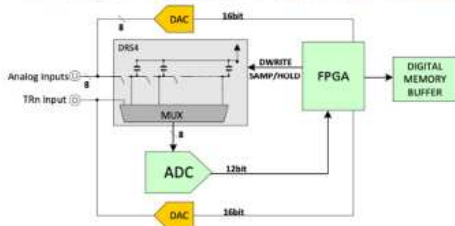


LAPPD side



DAQ system

WEINER VME crate:
CAEN V1718 controller board
CAEN V1742 Digitizer board with 32 readout channels

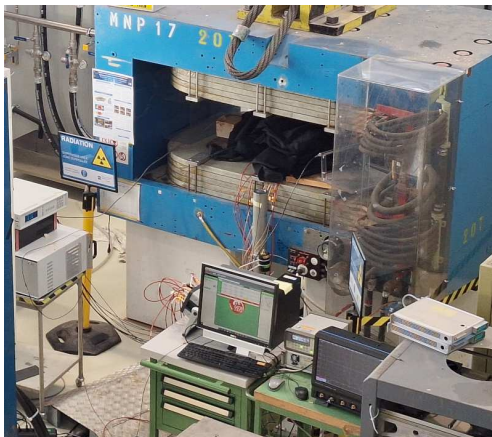


V1742 Board:

- > 4 DRS chips
- > 5 GS/s -> 200 ps
- > 32 Analog channels
- > 2 fast triggers (1 global trigger)
- > each channel has 1024 SCA (Cells)
- > one 12 bit ADC in each chip

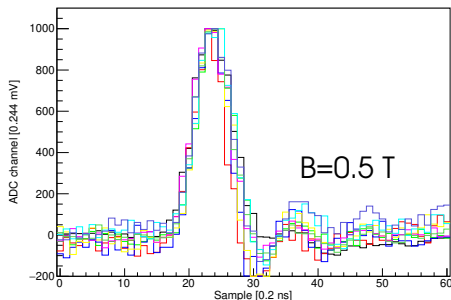
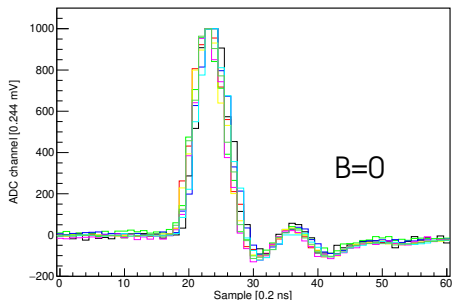
Entire setup

- LAPPD and dark box were covered with black clothes to reduce further ambient light background,
- electronics was installed at about 2 m from the magnet.



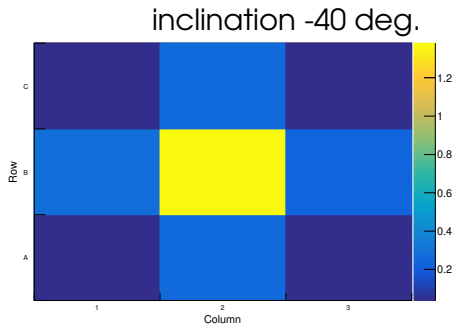
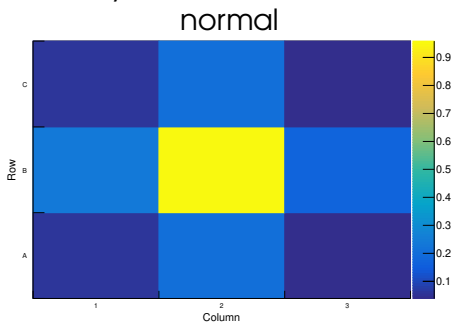
Measured LAPPD signals

- LAPPD risetime (20-80%) was about 0.45 ns,
- V1742 digitizer has $BW=0.5$ GHz \rightarrow 0.45 ns is its intrinsic limit on risetime (20-80%),
- LAPPD 6 mm pad has capacitance 1.6 pF, assuming 50Ω load we expected 80 ps,
- $B=0.5$ T field increased signal risetime on 25%.



2D maps of collected charge at B=0

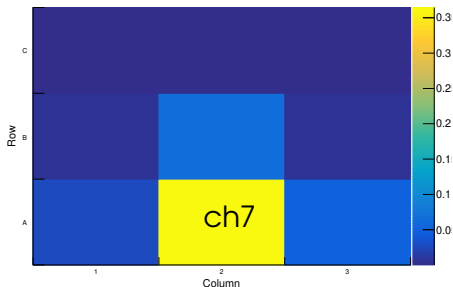
- 55% of charge is collected on the pad under fiber,
- different LAPPD inclinations at B=0 preserve the same charge map,
- after fiber movement the charge collection in all pads increased on 34%, 0.2 mm gap area fraction is just 6.35%, requiring main peak to be located at the edge of central pad, but the observed distribution is symmetric.



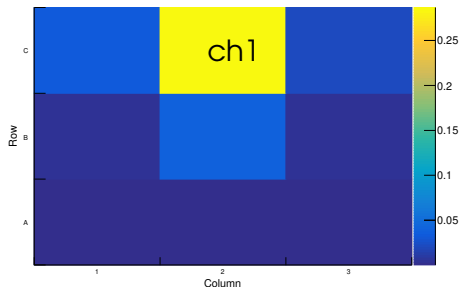
2D maps of collected charge at $B=0.5\text{ T}$

- at normal field the peak is still in central pad, but it collects 79%,
- inclination of field shifts the peak by about one pad and increases peak pad fraction to 85%.

inclination -40 deg.



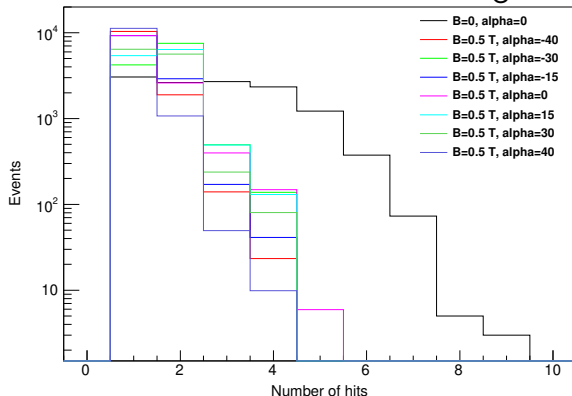
inclination $+40\text{ deg.}$



LAPPD hit multiplicity

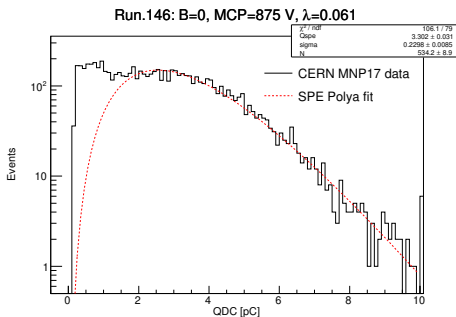
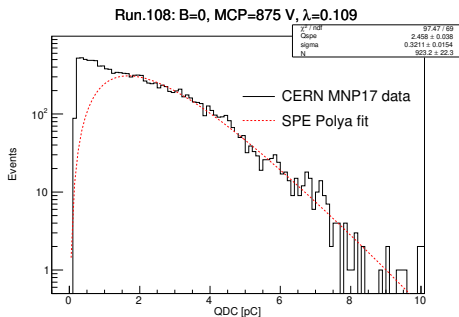
- at $B=0$ charge distribution is 2 times broader and pad hit multiplicity is larger (mean 2.8),
- at $B=0.5$ T all multiplicities are similar and the mean varies from 1.1 to 1.7.

Standard bias voltages



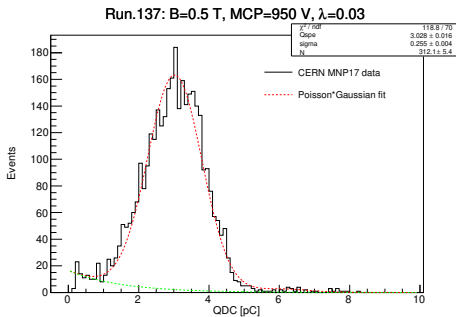
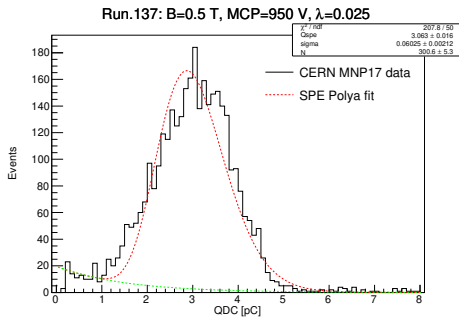
LAPPD collected charge at B=0

- datasheets of LAPPD N.153 at 875 V (50 V PC) gives gain of 8×10^6 , we expected SPE peak at 2.56 pC,
- the observed SPE peak at 2.46 ± 0.04 pC, $\sigma/\mu \sim 0.32$,
- $\theta = -30$ and -40 deg. peak at 3.3 pC (+34%),
- fit requires exponential component.



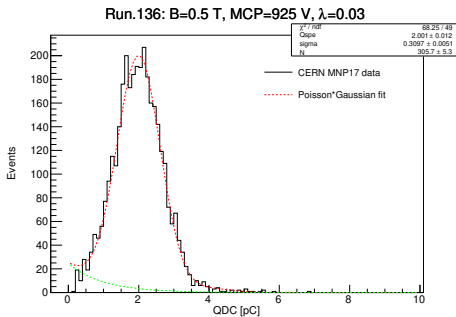
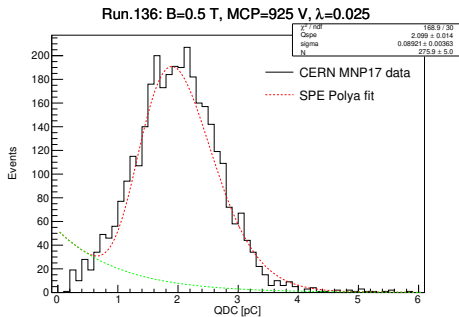
LAPPD collected charge at B=0.5 T MCP=950 V

- exponential tail is 10 times smaller (w.r.t. B=0),
- Polya shape gives 2 times larger χ^2 (w.r.t. Gaussian),
- $\sigma/\mu \sim 0.26$ (Gaussian) or 0.06 (Polya), number of secondaries $N_e \sim (\mu/\sigma)^2$: 15 or 278,
- SPE charge is compatible within uncertainties.



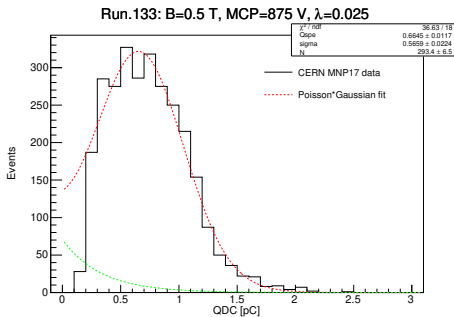
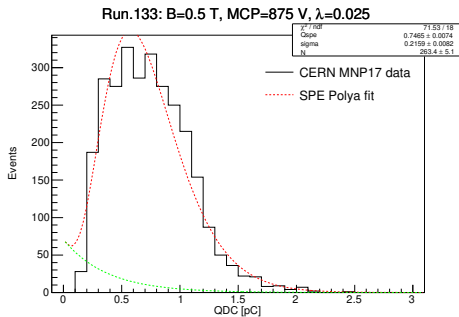
LAPPD collected charge at B=0.5 T MCP=925 V

- exponential tail is 10 times smaller (w.r.t. B=0),
- Polya shape gives 2 times larger χ^2 (w.r.t. Gaussian),
- $\sigma/\mu \sim 0.31$ (Gaussian) or 0.09 (Polya), number of secondaries $N_e \sim (\mu/\sigma)^2$: 10 or 123,
- SPE charge is compatible within uncertainties.



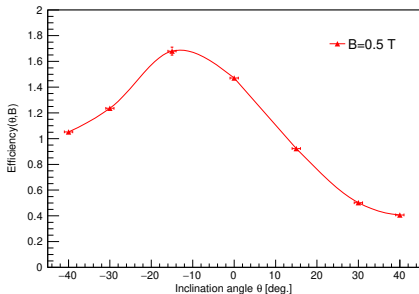
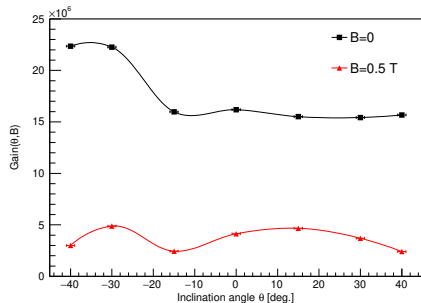
LAPPD collected charge at B=0.5 T MCP=875 V

- exponential tail is 10 times smaller (w.r.t. B=0),
- Polya shape gives 2 times larger χ^2 (w.r.t. Gaussian),
- $\sigma/\mu \sim 0.57$ (Gaussian) or 0.22 (Polya), number of secondaries $N_e \sim (\mu/\sigma)^2$: 3 or 21,
- Polya gives 13% larger SPE charge.



LAPPD gain and efficiency at 875 V

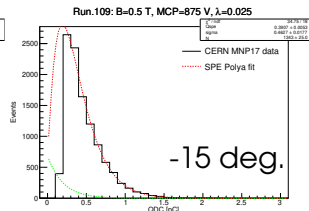
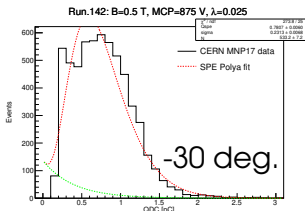
- gain estimated from Polya fit (Q_{spe} parameter/e),
- $\theta = -30, -40$ deg. peaks are higher, -15 deg. 40% lower,
- at ± 40 deg. gain drops by 35%,
- efficiency: ratio of Polya normalizations $B=0.5$ T/ $B=0$,
- at $B=0.5$ T Polya fits are not always good.



Fits at B=0.5 T, MCP=875 V

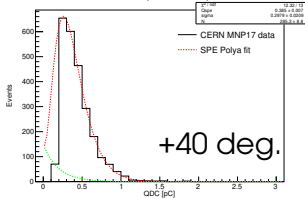
- at -30 deg. higher peak and large exponential,
- at -15 deg. lower peak and large exponential,
- fits ambiguous due to overlap with exponential.

-40 deg.



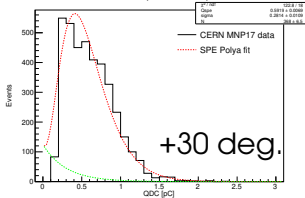
-15 deg.

Run.114: B=0.5 T, MCP=875 V, $\lambda=0.025$



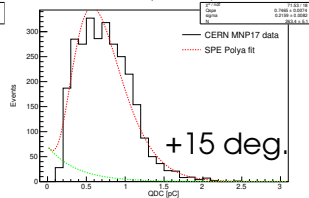
+40 deg.

Run.120: B=0.5 T, MCP=875 V, $\lambda=0.025$



+30 deg.

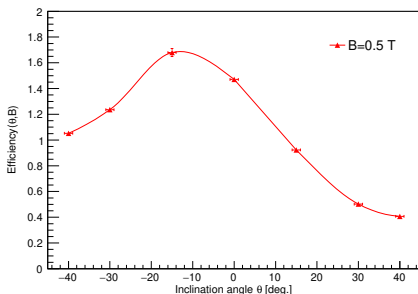
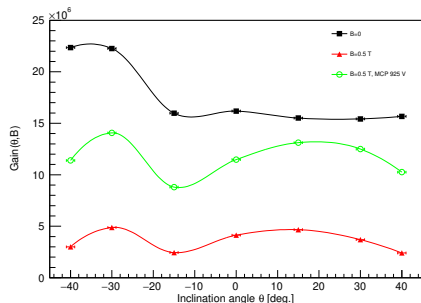
Run.133: B=0.5 T, MCP=875 V, $\lambda=0.025$



+15 deg.

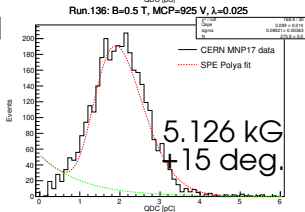
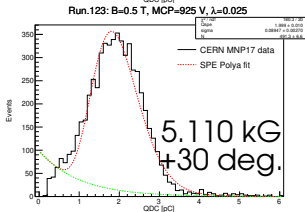
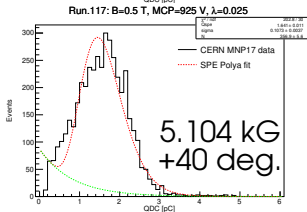
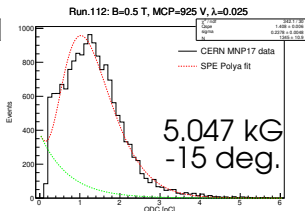
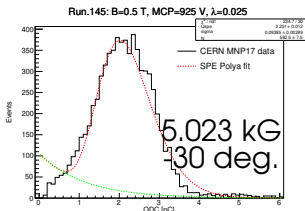
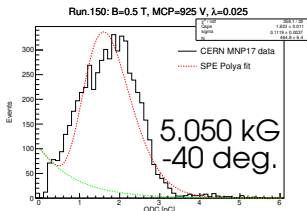
LAPPD gain and efficiency at 925 V

- confirm that at ± 40 deg. gain drops by 18%,
- $\theta = -15$ peak 30% lower (consistent with 875 V),
- gain variations of 20%,
- efficiency: ratio of Polya normalizations $B=0.5$ T/ $B=0$,
- at $B=0.5$ T Polya fits are not always good.



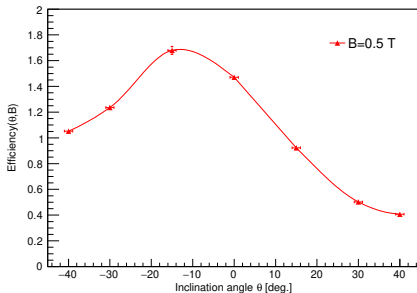
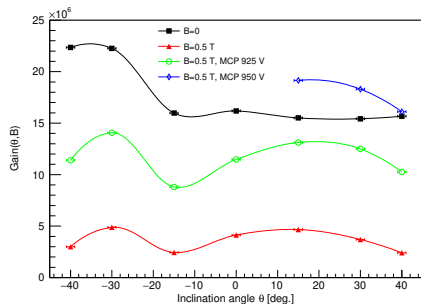
Fits at B=0.5 T, MCP=925 V

- peak positions are unambiguous,
- magnetic field variations $\leq 2\%$.



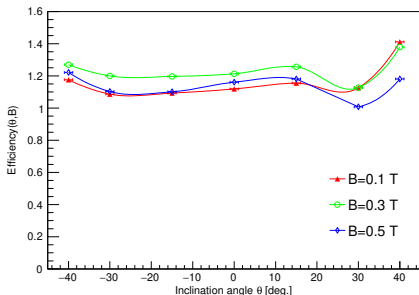
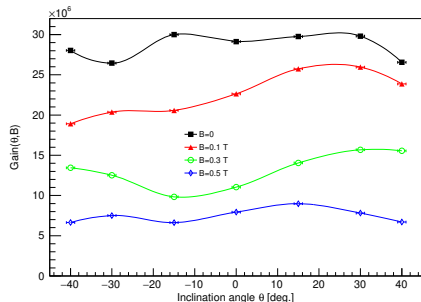
LAPPD gain and efficiency at 950 V

- confirm that at +40 deg. gain drops by 13%,
- efficiency: ratio of Polya normalizations $B=0.5\text{ T}/B=0$,
- at $B=0.5\text{ T}$ Polya fits are not always good.



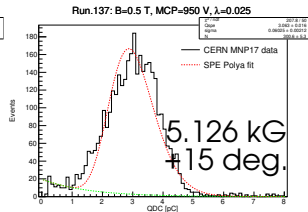
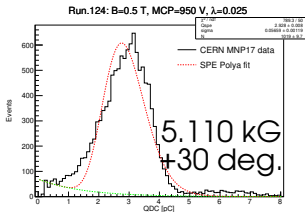
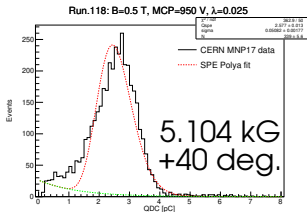
LAPPD gain and efficiency at 900 V, Photo-Cathode disconnected

- 1.7 times higher gain than at 875 V (both $B=0$ and $B=0.5$ T), datasheets suggest factor 2,
- efficiency independent of angle and B-field,
- minimum at -15 deg. the same as with Photo-Cathode.



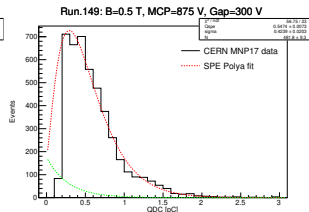
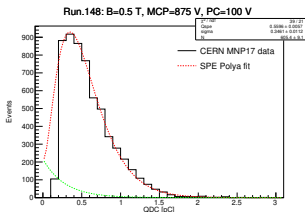
Fits at B=0.5 T, MCP=950 V

- peak positions are unambiguous,
- magnetic field variations $\leq 0.4\%$.



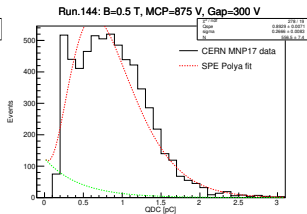
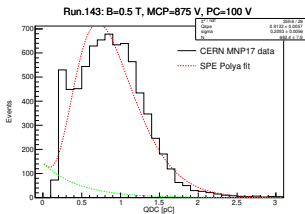
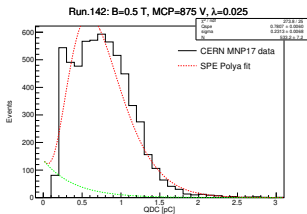
Fits at B=0.5 T, MCP=875 V, $\theta = -40$ deg.

- PC=100 V: gain +17%,
- Gap=300 V: gain +14%.



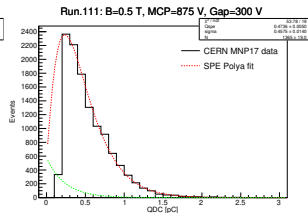
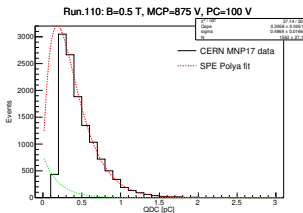
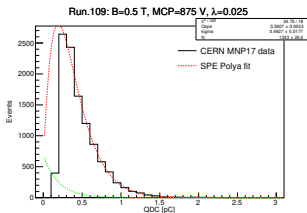
Fits at B=0.5 T, MCP=875 V, $\theta = -30$ deg.

- PC=100 V: gain +17%,
- Gap=300 V: gain +14%.



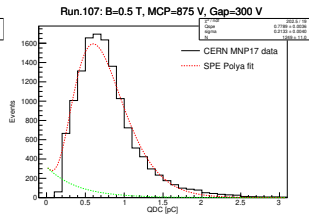
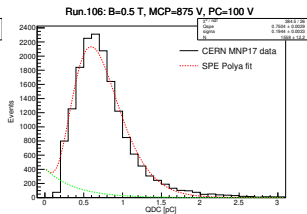
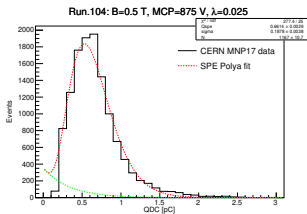
Fits at B=0.5 T, MCP=875 V, $\theta = -15$ deg.

- PC=100 V: gain +2%,
- Gap=300 V: gain +21%.



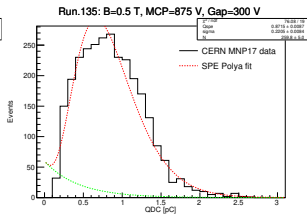
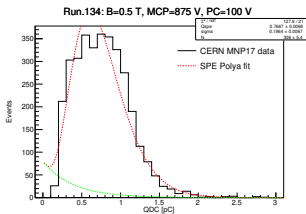
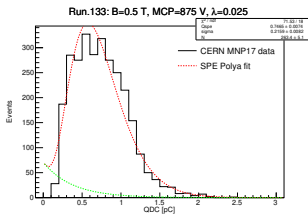
Fits at B=0.5 T, MCP=875 V, $\theta = 0$ deg.

- PC=100 V: gain +14%,
- Gap=300 V: gain +18%.



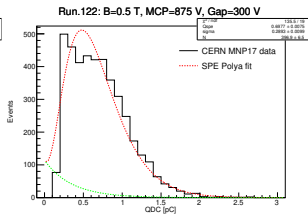
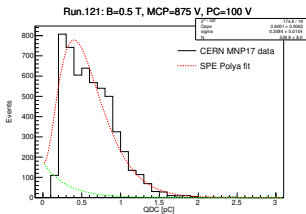
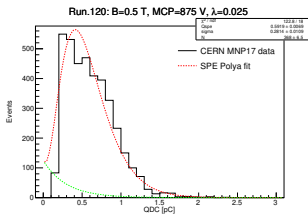
Fits at B=0.5 T, MCP=875 V, $\theta = 15$ deg.

- PC=100 V: gain +3%,
- Gap=300 V: gain +17%.



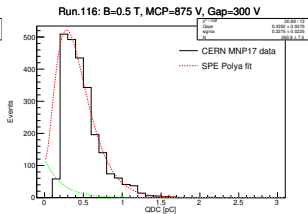
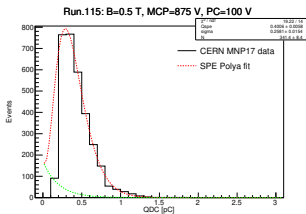
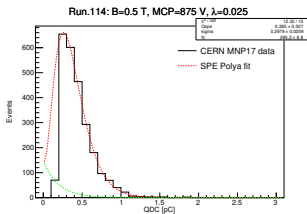
Fits at B=0.5 T, MCP=875 V, $\theta = 30$ deg.

- PC=100 V: gain +2%,
- Gap=300 V: gain +18%.



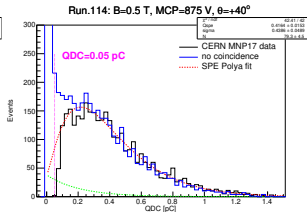
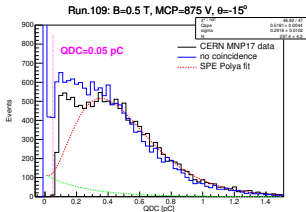
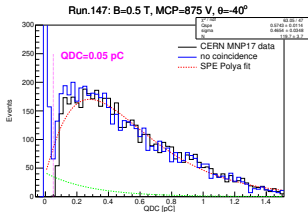
Fits at B=0.5 T, MCP=875 V, $\theta = 40$ deg.

- PC=100 V: gain +4%,
- Gap=300 V: gain +14%.



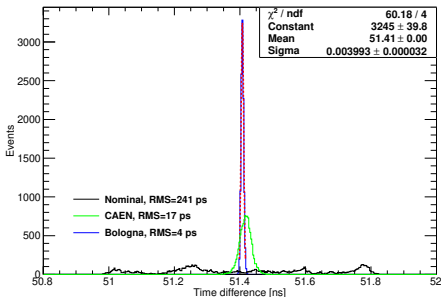
Lowest feasible threshold

- integrating 3 ns interval 20 ns after the laser synch gives an idea of S/N,
- for $\theta < +30$ noise rises < 0.025 pC, corresponding to 5 mV threshold,
- for $\theta \geq +30$ noise rises < 0.05 pC, corresponding to 10 mV threshold,
- for the reference the baseline RMS is about 2 mV,
- $\theta = -15$ deg. has second peak at low QDC ≈ 0.13 pC.



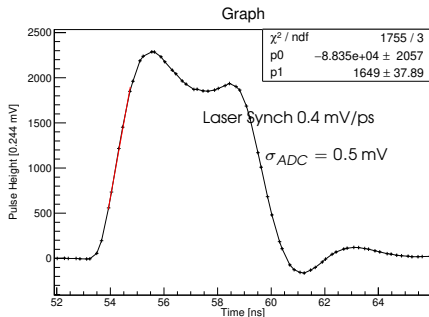
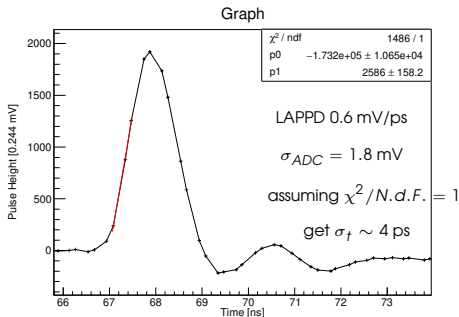
DRS4 timing calibrations

- we used timing calibration procedure developed by Vincenzo Vagnoni (INFN Bologna),
- validation of calibration gave 4 ps residual resolution,
- calibrated delays between cells are around 150/250 ps for even/odd cells,
- timing corrections are significant: 50 ps broadening.



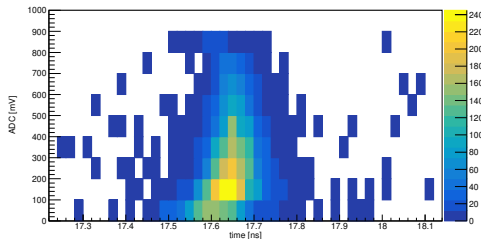
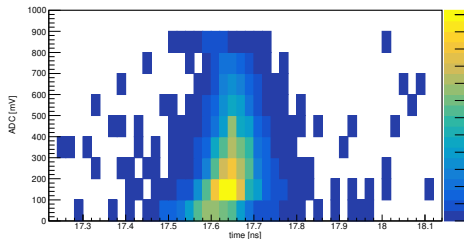
LAPPD time measurements

- acquired raw waveforms (no CAEN on-line corrections) were converted in TGraphs with variable delays between samples (using Bologna calibrations),
- to measure time we fitted pulse rising edge in the region of 50% height with a linear function,
- time was determined as the crossing point of 50% height by the linear fit function.



LAPPD PH-corrections on time

- linear function approximation in the fit leads to systematic effects on the time difference,
- time difference depends on signal Pulse Heights,
- in LAPPD time drift is about 0.2 ps/mV, mostly < 100 mV,
- but this correction is visible only in runs without Photo-cathode.



SPE timing results

- time difference distributions mostly appeared as a Gaussian-like peak,
- Gaussian fit was used to determine timing resolution,
- movement of optical fiber reduced resolution by a factor of 2, and shifted mean by -1.6 ns (34 cm),
- for $\theta = -40$ and -30 deg. SPE timing was 135 ps at $B=0$, and 145 ps at $B=0.5$ T (datasheets 70 ps),
- for other angles varies in range 300-400 ps.

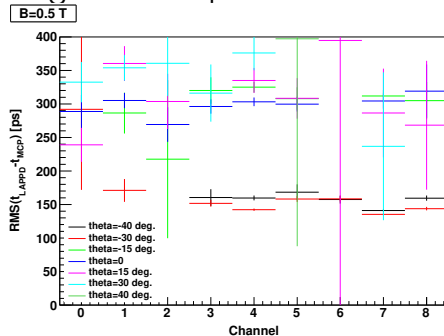
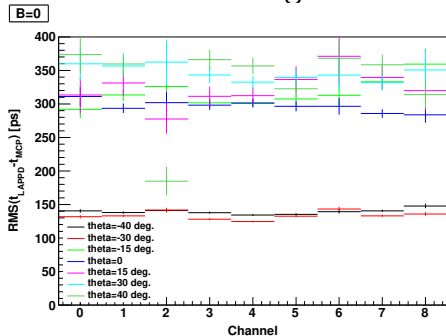
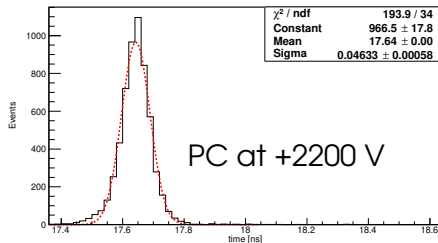
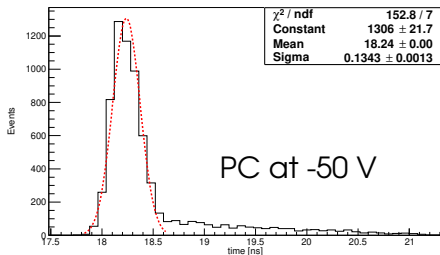


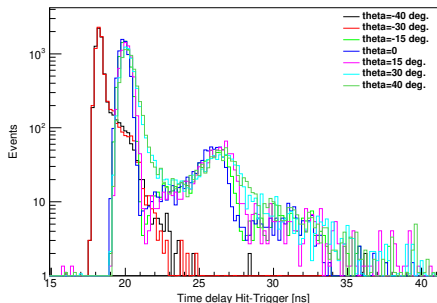
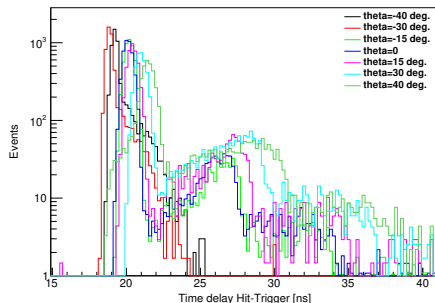
Photo-cathode bias effect

- data taken with disconnected Photo-cathode (+2200 V w.r.t. entry MCP) show 50 ps RMS,
- with Photo-cathode RMS is at least factor 3 worse, and mean shifted by +0.6 ns (time electron travels in 50 V/1.4 mm electric field is 0.58 ns),
- PicoQuant LDH-P-C-405 laser head has 44 ps FWHM pulse (19 ps RMS), thus fiber uncertainty 40 ps,
- initial electron energy 7 times lower than acceleration term, why RMS different?



Coincidence time

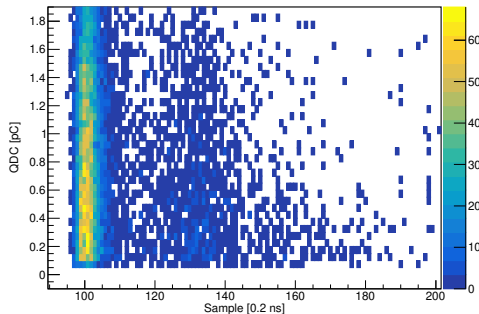
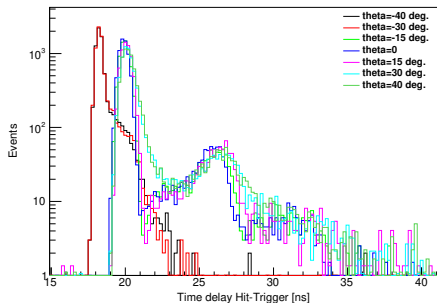
- before fiber movement we had secondary peak at +6.5 ns (and small one at +13 ns),
- after fiber movement it disappeared,
- the main peak has r.h.s. tail up to about 3 ns.

B=0**B=0.5 T**

Coincidence time vs QDC

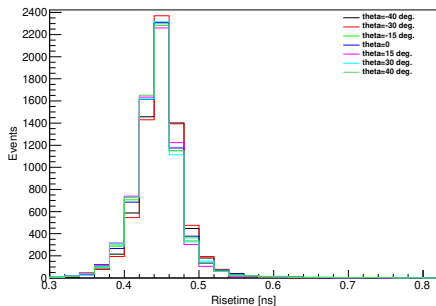
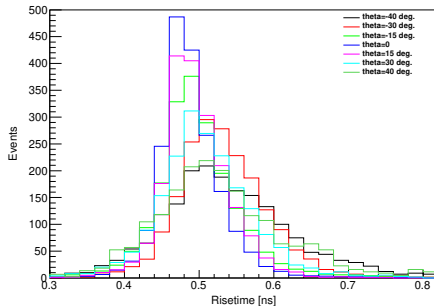
- the secondary peak appears for all charge values,
- it is not for small signals only.

B=0



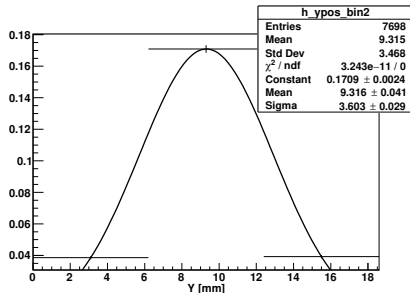
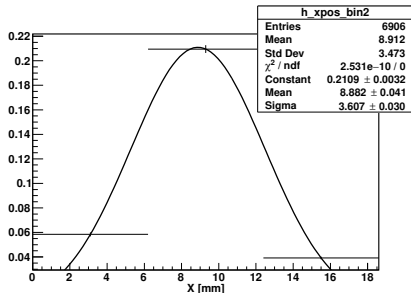
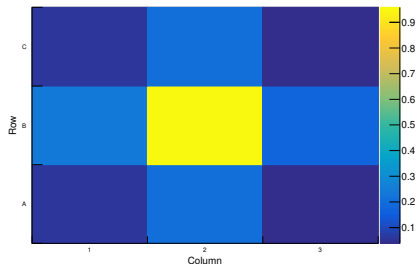
Rise-time vs B

- at $B=0$ all risetimes are about 0.45 ns (V1742 limit),
- at $B=0.5$ T risetime depends on angle:
0.48 ns at 0 deg.,
0.52 ns at 40 deg.

B=0**B=0.5 T**

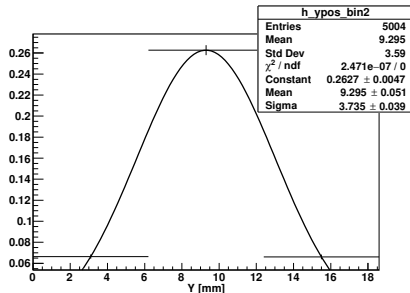
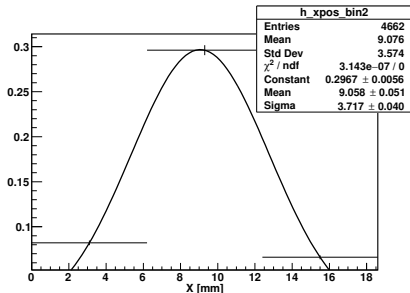
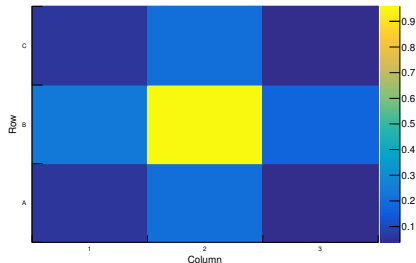
Spacial charge distribution $B=0$, $\theta = 0$ deg.

- spot in central pad (ch4),
- all angles in agreement,
- RMS about 3.6 mm.



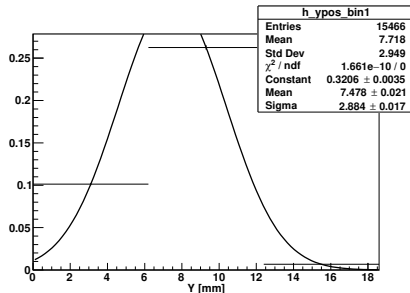
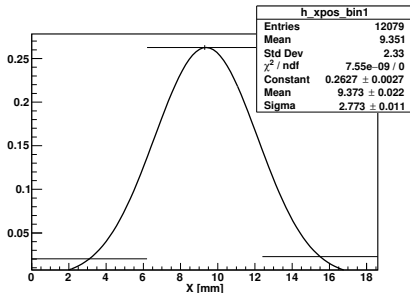
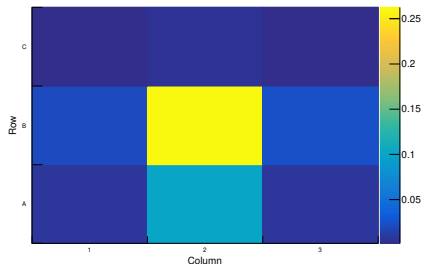
Spacial charge distribution $B=0$, $\theta = -40$ deg.

- offset in X:
 $+0.2 \pm 0.05$ mm,
- offset in Y:
 -0.02 ± 0.05 mm,
- within uncertainties
same position.



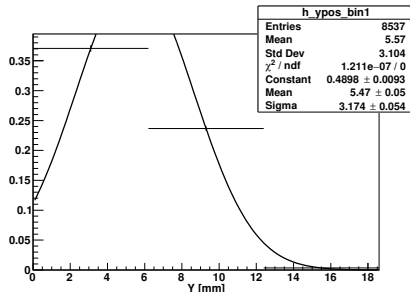
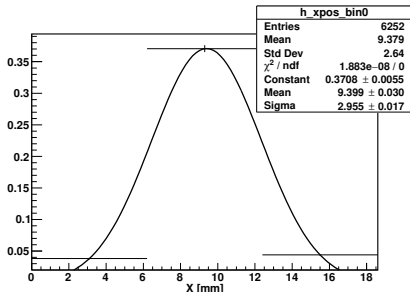
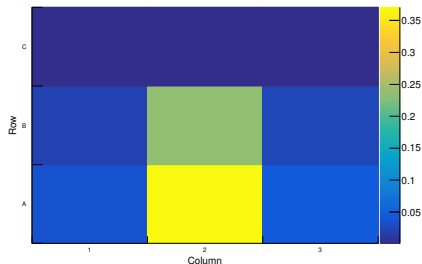
Spacial charge distribution $B=0.5\text{ T}$, $\theta = -15\text{ deg}$.

- offset in X: $+0.3 \pm 0.2\text{ mm}$,
- offset in Y: $-1.8 \pm 0.05\text{ mm}$,
- peak still in central pad.



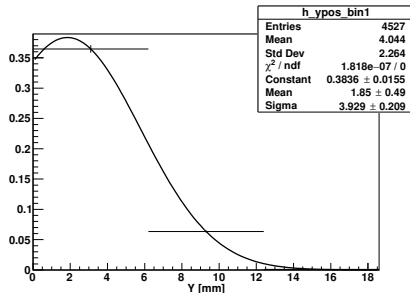
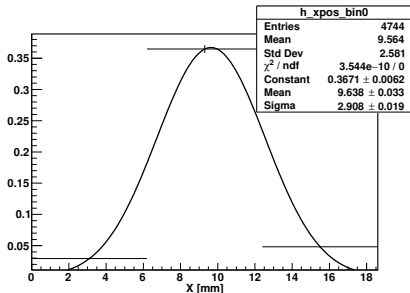
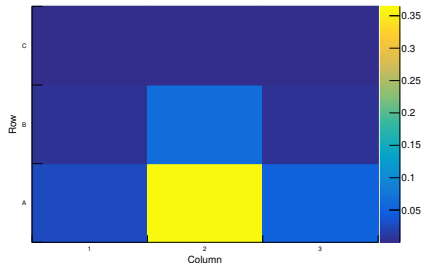
Spacial charge distribution $B=0.5\text{ T}$, $\theta = -30\text{ deg}$.

- offset in X:
+0.5±0.05 mm,
- offset in Y: -3.8±0.05 mm,
- peak in first pad - need one pad more!



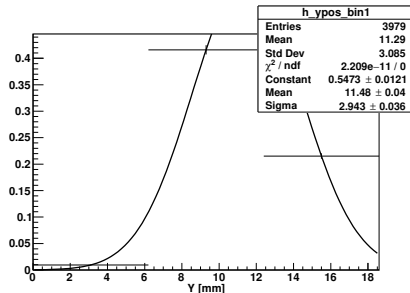
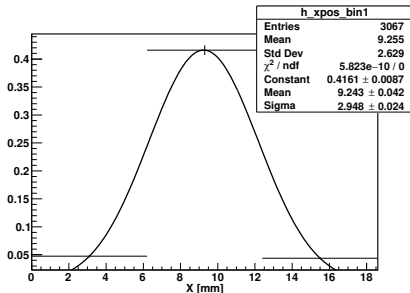
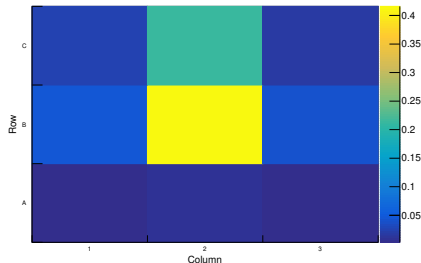
Spacial charge distribution $B=0.5\text{ T}$, $\theta = -40\text{ deg}$.

- offset in X:
+0.55±0.1 mm,
- offset in Y: -7.4±2 mm,
- peak in first pad - need one pad more!



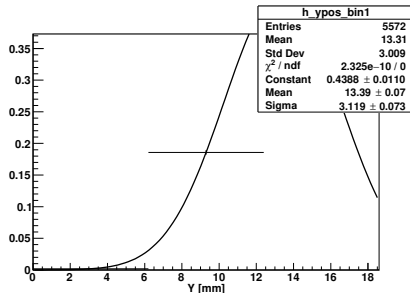
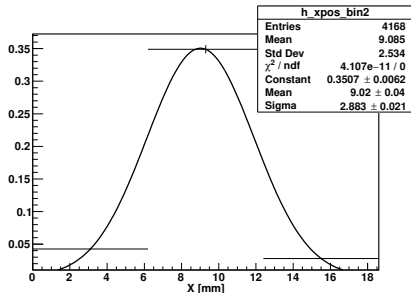
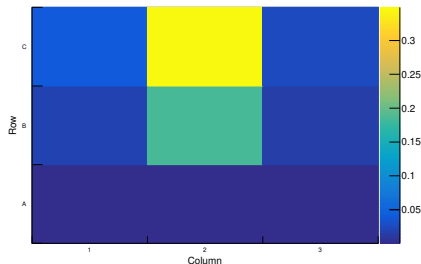
Spacial charge distribution $B=0.5\text{ T}$, $\theta = 15\text{ deg}$.

- offset in X: $+0.3 \pm 0.2\text{ mm}$,
- offset in Y: $+2.2 \pm 0.05\text{ mm}$,
- peak still in central pad.



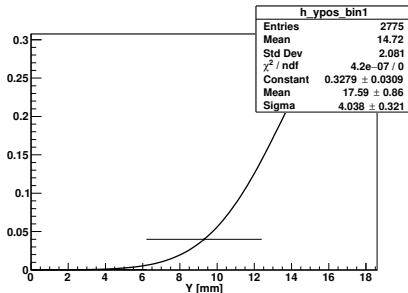
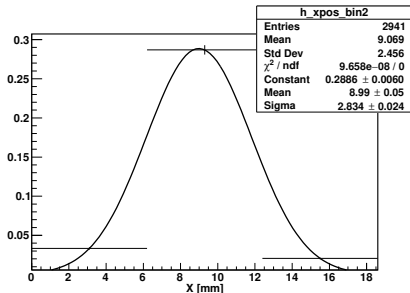
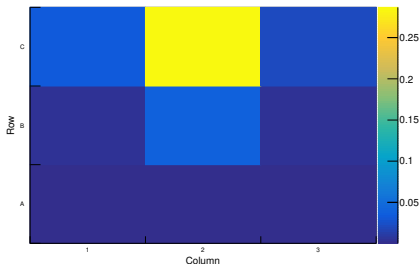
Spacial charge distribution $B=0.5\text{ T}$, $\theta = 30\text{ deg}$.

- offset in X:
 $+0.5 \pm 0.05\text{ mm}$,
- offset in Y:
 $+4.1 \pm 0.05\text{ mm}$,
- peak in first pad - need one pad more!



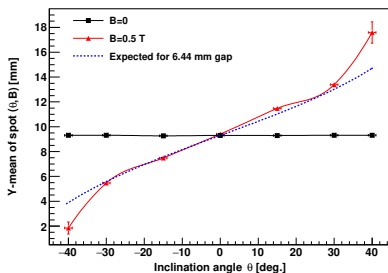
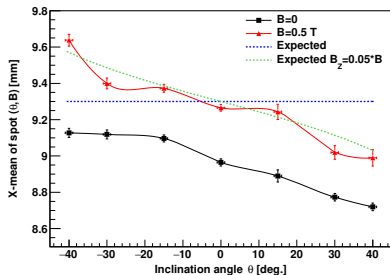
Spacial charge distribution $B=0.5\text{ T}$, $\theta = 40\text{ deg}$.

- offset in X:
 $+0.55 \pm 0.1\text{ mm}$,
- offset in Y: $+8.3 \pm 2\text{ mm}$,
- peak in first pad - need one pad more!



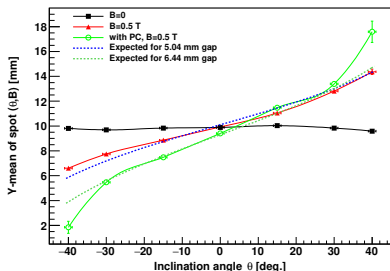
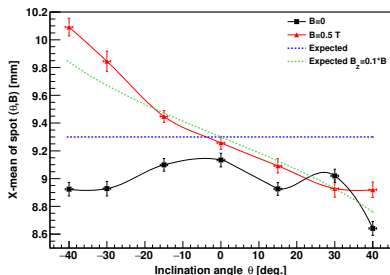
Collected charge spot position in B-field

- X-position is offset by -0.3 mm and moves with angle on 0.6 mm, at B=0.5 T it jumps by +0.2 mm;
- Y-position is well centered at expected 9.3 mm, at B=0.5 T it follows the expected $6.44 \cdot \tan(\theta)$ distribution except ± 40 deg. which are highly uncertain;
- -40 and -30 deg. are consistent with others;
- at ± 20 deg. offset = 2.4 mm, spot will be almost equally shared between central and nearby pads.



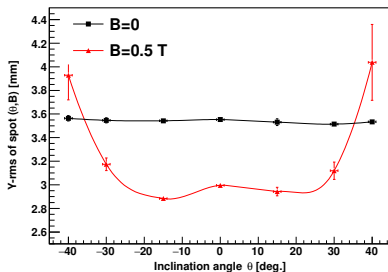
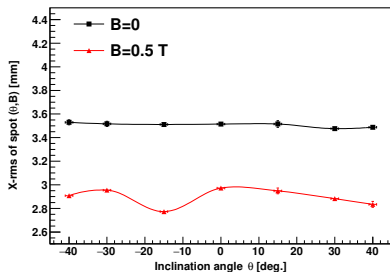
Collected charge spot position without PC

- X-positon is offset by -0.3 mm and 10% B-filed effect;
- Y-position is offset by +0.5 mm, at B=0.5 T it follows the expected $5.04 \cdot \tan(\theta)$ distribution;
- 1.4 mm difference in total gap height (with and without PC) is clearly visible.



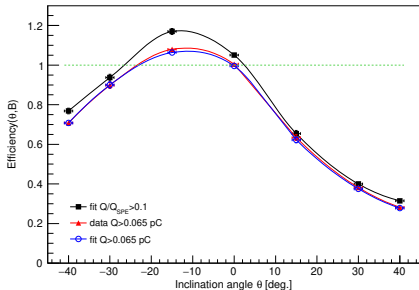
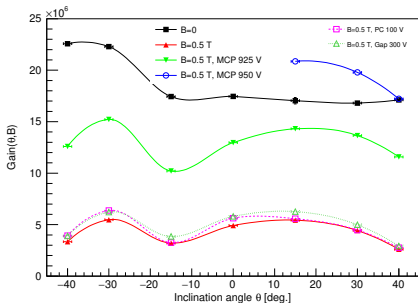
Collected charge spot RMS in B-field

- X-resolution is 3.5 mm at $B=0$, at $B=0.5$ T it reduces to 2.9 mm (-17%);
- Y-resolution is consistently 3.5 mm at $B=0$, at $B=0.5$ T it reduces consistently to 2.9 mm (-17%), except uncertain edges ± 40 deg.;
- -40 and -30 deg. are consistent with others.



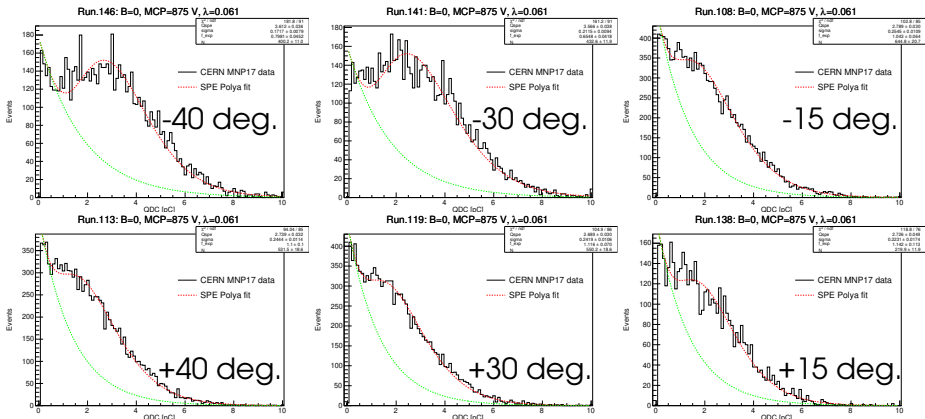
new LAPPD gain and efficiency at 875 V

- confirm that at ± 40 deg. and -15 deg. gain drops by -40% ,
- efficiency: ratio of data or fit $B=0.5$ T/ $B=0$ with pC or PE thresholds,
- all efficiency estimates are similar.



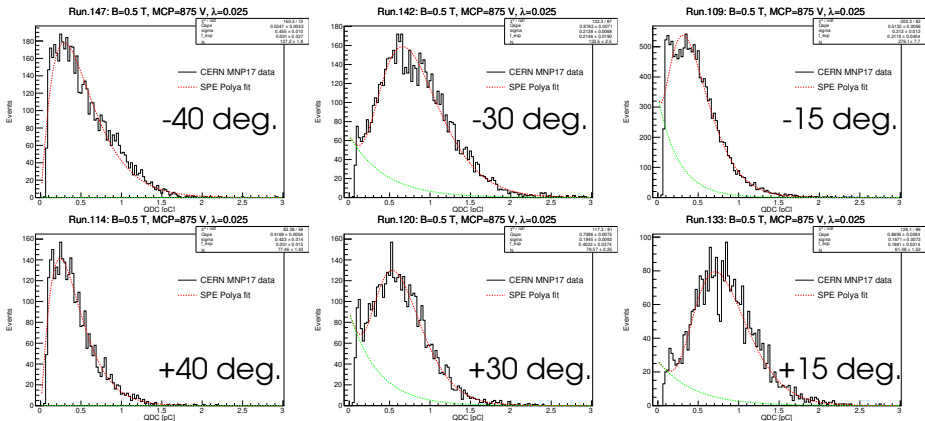
B=0 fits used in gain

- large exponential contribution;
- peak position is model-dependent (exponent shape), except for -40 and -30 deg.



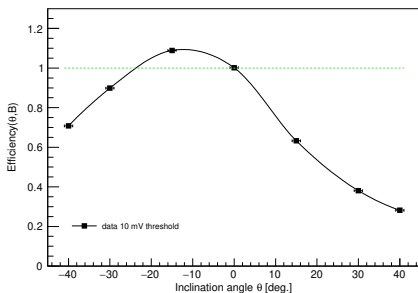
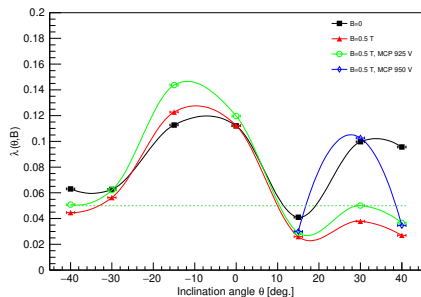
B=0.5 T fits used in gain

- at ± 40 deg. threshold rise in data too steep;
- at -15 deg. double Polya (also very steep threshold rise).



Simple LAPPD gain and efficiency at 875 V

- our goal was to take data at $\lambda = 0.05$, but some runs were taken at $\lambda \simeq 0.10$;
- at $\lambda \simeq 0.10$ the probability to observe 2 PE events is ≈ 0.05 (at $\lambda = 0.05$ it is 2 times smaller ≈ 0.025);
- efficiency obtained simply from the ratio of coincidence events at $B=0.5$ T/ $B=0$ in good agreement with more sophisticated estimates.



Charge fraction collected on the spot pad

- at B=0 spot pad collects about 0.55 of total charge;
- at B=0.5 T this fraction increases up to 0.7 (smaller width), but varies with angle;
- at ± 40 deg. the extrapolation into missing pad indicates that we are losing about 5-7% of charge, insufficient to recover -40% gain loss;
- instead the peak position from the fixed width fit comes on the expected $\tan \theta$ -line.

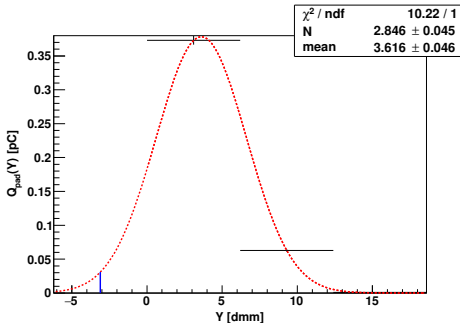
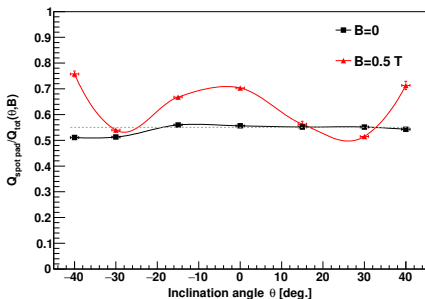
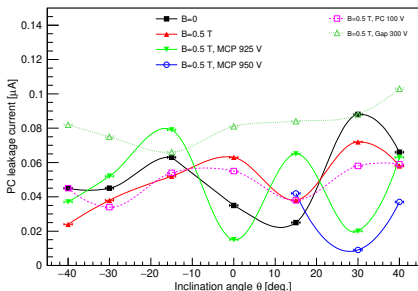


Photo-Cathode leakage current

- for 50 kHz/cm² DCR expected: 2×10^7 e/s=3.2 pA,
- observed current around 50 nA, four orders of magnitude larger,
- variations by factor of 2, high for 300 V gaps,
- almost no difference between 50 and 100 V at PC,
- PC isolation leakage:
 PC-Entry MCP =1 G Ω (depend on PC V) - excluded,
 PC-GND =44 G Ω - most likely.

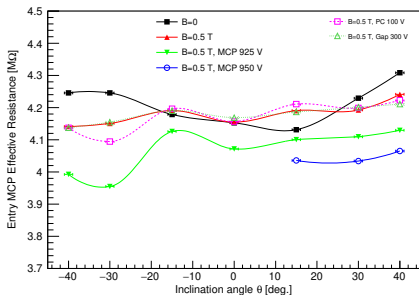
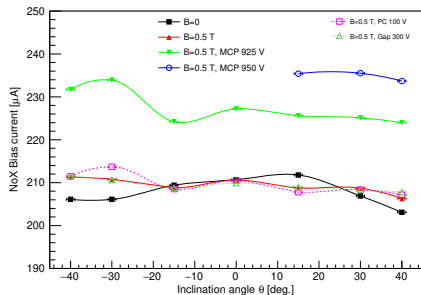


Entry MCP leakage current and resistance

- effective resistance of Entry MCP was $R_0 = 4.2 \text{ M}\Omega$,

$$R_{\text{eff}}(V, I) = \frac{V_{\text{set}}}{I_{\text{leakage}}}$$

- resistance decreases with High Voltage,
- B-field had small effect.

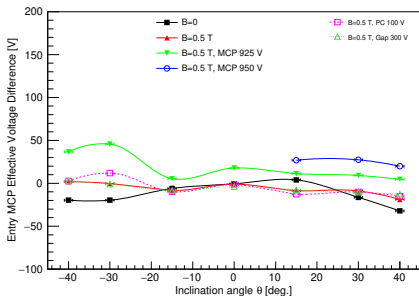
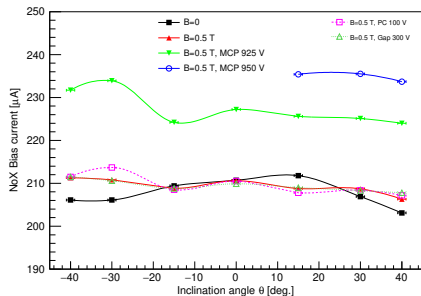


Entry MCP leakage current and voltage

- effective voltage deviation of Entry MCP was estimated assuming series connection:

$$\Delta V_{eff}(V, I) = I_{leakage} \times R_0 - V_{set}$$

- 5 μA deviation gives 20 V voltage offset,
- at higher MCP bias resistance changes.

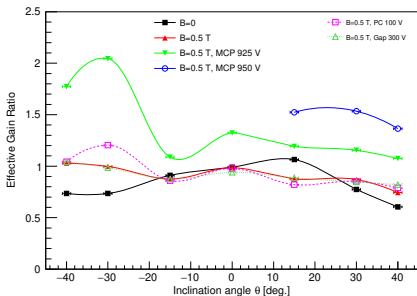
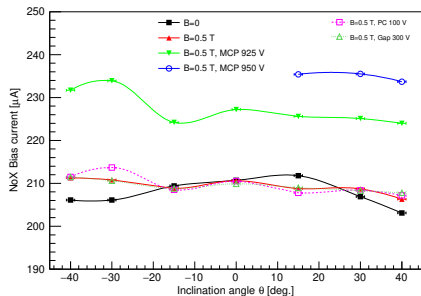


Entry MCP leakage current and gain

- effective gain ratio of Entry MCP was estimated:

$$\frac{G_{eff}(V, I)}{G_0} = \exp \left\{ \frac{d \ln G}{dV} \frac{(I_{leakage} \times R_0 - V_0)}{2} \right\}$$

- 5 μA deviation gives 30% gain offset,
- B-field had small effect.

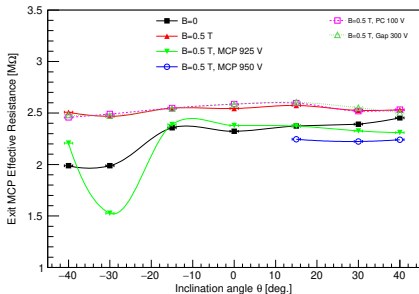
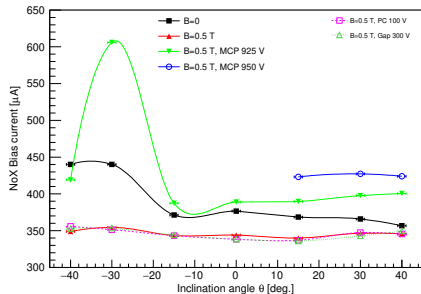


Exit MCP leakage current and resistance

- effective resistance of Exit MCP was $R_0 = 2.2 \text{ M}\Omega$,

$$R_{\text{eff}}(V, I) = \frac{V_{\text{set}}}{I_{\text{leakage}}}$$

- resistance decreases with High Voltage,
- +10% B-field effect, not seen in Entry MCP.

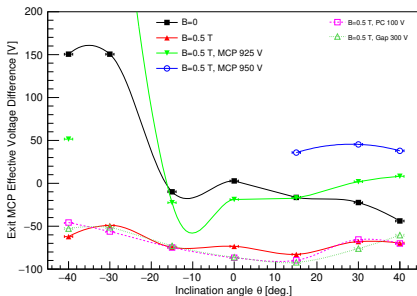
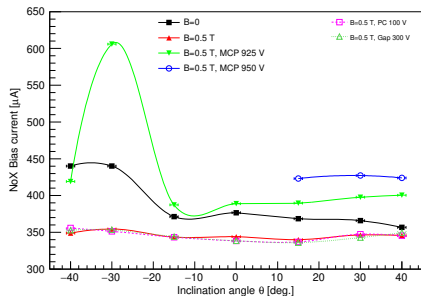


Exit MCP leakage current and voltage

- effective voltage deviation of Exit MCP was estimated assuming series connection:

$$\Delta V_{eff}(V, I) = I_{leakage} \times R_0 - V_{set}$$

- 20 μA deviation gives 50 V voltage offset,
- at higher MCP bias resistance changes.

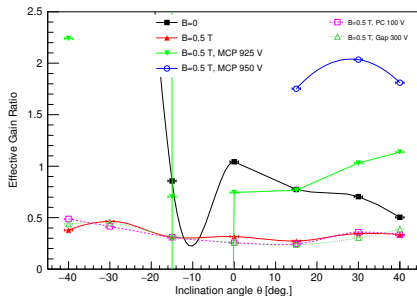
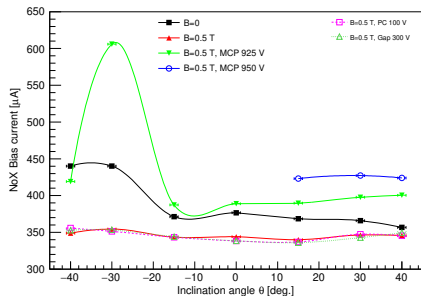


Exit MCP leakage current and gain

- effective gain ratio of Exit MCP was estimated:

$$\frac{G_{eff}(V, I)}{G_0} = \exp \left\{ \frac{d \ln G}{dV} \frac{(I_{leakage} \times R_0 - V_0)}{2} \right\}$$

- 20 μA deviation gives 50% gain offset,
- 0.5 T B-field gives -50% effect, not seen in Entry MCP.



Lessons learned I

- 1 avoid touching optical fiber: 35% variation of gain,
- 2 at low gain ambiguous SPE-charge reconstruction: higher MCP voltage in B-field? But it is unstable at $B=0$.
- 3 extrapolating to $B=1.5$ T expect $<2\%$ gain (at $B=0.5$ T was 25%), QDC shoulder will shrink from 0.7-1 pC ($B=0.5$ T) to 0.04-0.06 pC. This is below actual threshold of 0.2 pC. Can we measure at much lower threshold? Or shall we increase laser intensity and measure 10 PE peak?
- 4 at ± 30 deg. charge spot moves to the edge of instrumented 3x3 pad array: solder remaining 4 pads and add SMA connectors!
- 5 angular gain variations are seen only around $\theta = -13$ deg. and $|\theta| > 40$ deg.: enough measure at 0, ± 13 deg., ± 40 deg. and higher.

Lessons learned II

- 1 bad timing resolution with PC not understood,
- 2 does it depend on the laser intensity?
- 3 for $NA=0.22$, $200\ \mu\text{m}$ core straight fiber TIR every $\geq 1.3\ \text{mm}$, corresponding to $\geq 6.4\ \text{ps}$,
- 4 $RMS \sim 40\ \text{ps}$ residual (observed without PC) suggests $6.3\ \text{TIRs FWHM}$, or $8\ \text{mm}$ of fiber length,
- 5 test (in Trieste) fibers of different length and different core sizes,
- 6 test (in Trieste) time resolution as a function of fiber bending,
- 7 test (in Trieste) time resolution as a laser intensity,
- 8 test (in Trieste) charge collection as a function of fiber bending.

Summary

- tested 10 μm pore LAPPD N.153 capacitively coupled to custom readout board with 6 mm pads,
- tests performed at CERN MNP-17 magnet at 0.5 T,
- in 0.5 T field gain was reduced by factor 0.25,
- gain reduction was almost independent of angle, except $\theta = -13$ deg. and $|\theta| \geq 40$ deg.,
- gain reduction in 0.5 T field can be compensated by about 60 V increase of MCP bias voltage, but LAPPD dark current might become unstable,
- timing resolution was not understood (but B=0.5 T effect is relatively small),
- spacial resolution improves in B=0.5 T field.

References

- 1 M. Amarian *et al.*, "The CLAS forward electromagnetic calorimeter", *Nucl. Instr. and Meth.* **A460**, 239 (2001).
- 2 M. Guillo, "EC Time Calibration Procedure for photon runs in CLAS", CLAS-Note-2001-014, 2001.
- 3 M. Osipenko, "Geometrical alignment of CLAS DCs using tracks with constrained vertex", CLAS-Note-2019-001, 2019.

Backup slides

Polya approximation

- Polya distribution approximates events following a sequence of Poisson processes proceeding with slightly different rate parameters,
- For a large number of multiplied electrons, the Polya distribution approaches a Gamma distribution:

$$\text{Polya}(q; \mu, b) = \frac{1}{b\mu\Gamma(\frac{1}{b})} \left(\frac{q}{b\mu}\right)^{\frac{1}{b}-1} e^{-\frac{q}{b\mu}}$$

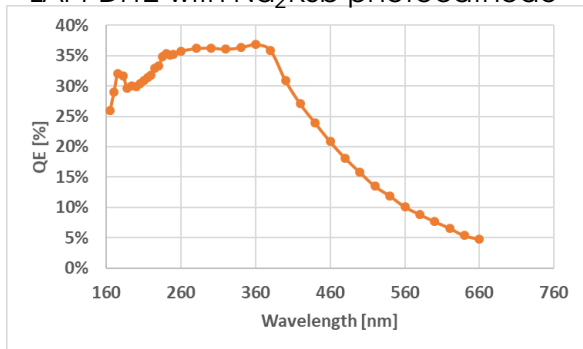
μ is the distribution mean, and b is unitless relative gain variance.

LAPPD Quantum Efficiency

- In wavelength range 180-400 nm QE of LAPPD is > 30%,
- numerical convolution $dN/d\lambda(\lambda)$ and $QE(\lambda)$: 33.6 p.e./mm.
- analytic estimate of Cherenkov p.e. yield assuming average $QE=30\%$:

$$N_\gamma = 0.0256 * \left\{ \frac{1}{160nm} - \frac{1}{560nm} \right\} * 0.30 = 34 \frac{p.e.}{mm},$$

LAPPD.12 with Na_2KSb photocathode



Optical fiber propagation time variance

- laser head LDH-P-C-405 operates at 405 nm,
- quartz refractive index $n(405 \text{ nm}) = 1.4698$, light group velocity $v_g \simeq 21 \text{ cm/ns}$,

- optical fiber NA=0.22 maximum photon angle inside core:

$$\theta_{core}^{max} = \text{asin}\left(\frac{NA}{n_{core}}\right) = 8.6^\circ,$$

- fiber length traveled by a photon between TIRs in $D = 200 \mu\text{m}$ fiber:

$$l_{TIR} \geq \frac{D}{\tan \theta_{core}^{max}} = 1.3 \text{ mm},$$

- photon path length variation (inclined-straight):

$$\frac{\frac{l_{TIR}}{\cos \theta_{core}^{max}} - l_{TIR}}{l_{TIR}} = 0.0114,$$

- assuming flat angular distribution (for SM NA=0.12 fiber 3.4 times smaller): $RMS = \frac{0.0114}{\sqrt{12}} \frac{1 \text{ m}}{21 \text{ cm/ns}} = 16 \text{ ps}$.